

1. Device Name VC-TCXO
2. Model Name DSA321SDN
3. Nominal Frequency 24.000 MHz
4. Mass 0.03g max.
5. Absolute Maximum Ratings

	Item	Symbol	Rating	unit
1	Supply Voltage	V _{CC}	-0.3~+4.6	V
2	Storage Temperature Range	T _{STG}	-40~+85	°C

6. Recommended Operating Conditions

	Item	Symbol	min.	typ.	max.	unit
1	Supply Voltage	V _{CC}	+2.85	+3.0	+3.15	V
2	Load Impedance (resistance part) (parallel capacitance)	L _{LOAD_R}	9	10	11	kΩ
		L _{LOAD_C}	9	10	11	pF
3	Control Voltage Range	V _{CONT}	+0.5	+1.5	+2.5	V
4	Operating Temperature Range	T _{OPR}	-30	-	+85	°C

7. Electrical Characteristics

(T_A=-30~+85°C, L_{LOAD_R}/C=10kΩ//10pF, V_{CC}=+3.0V, V_{CONT}=+1.5V, unless otherwise noted)

	Item	Conditions	Limits			unit	Notes
			min.	typ.	max.		
1	Current Consumption		-	-	+1.5	mA	
2	Output Level		0.8	-	-	V _{P-P}	1
3	Symmetry	GND level (DC cut)	40/60	-	60/40	%	
4	Frequency Stability 1.Tolerance	At Shipping Ref. to Nominal Frequency	-	-	±0.5	ppm	2
		After 2 times reflow Ref. to Nominal Frequency	-	-	±1.5	ppm	2,3
	2.vs Temperature	T _A =-30~+85°C Ref. to Frequency (T _A =+25°C)	-	-	±0.5	ppm	
	3.vs Supply Voltage	V _{CC} =+3.0V±5%	-	-	±0.3	ppm	
	4.vs Load Variation	L _{LOAD_R} /C=(10kΩ//10pF)±10%	-	-	±0.2	ppm	
	5.vs Aging	T _A =Room ambient	-	-	±1.0	ppm/year	
5	Start Up Time	@90% of final V _{out} level	-	-	2.0	ms	
6	Frequency Control 1.Control Range	V _{CONT} =+1.5V±1.0V	±9	-	±15	ppm	4
	2.Input Resistance		500	-	-	kΩ	
7	SSB Phase Noise	Relative to f ₀ level offset 1kHz	-	-	-135	dBc/Hz	

Notes

1. Clipped sine wave (DC-coupled)
2. T_A=+25°C
3. Please leave after reflow in 2h or more at room ambient.
4. Positive slope (Frequency becomes high in proportion to frequency control voltage.)

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Outline



Marking

unit: mm

9. Measurement Circuit



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